

Infra-red sub-wavelength imaging

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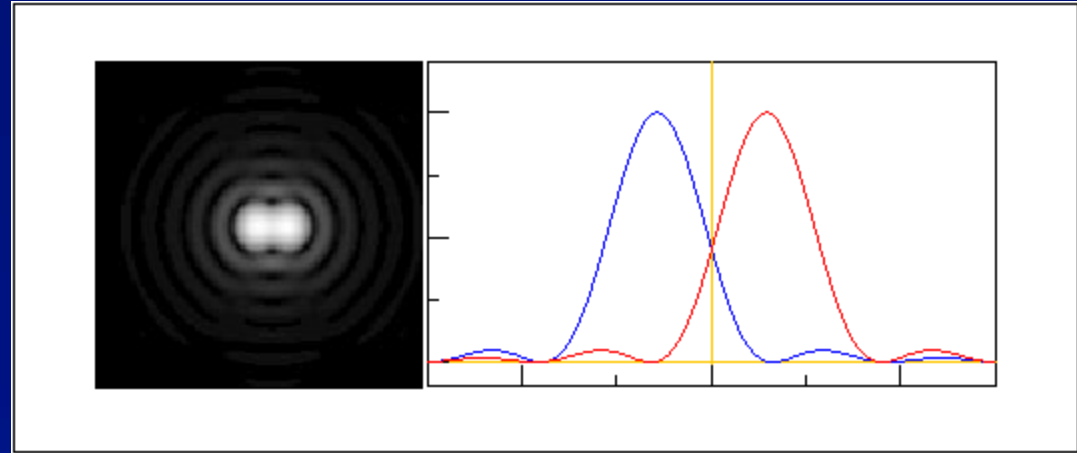
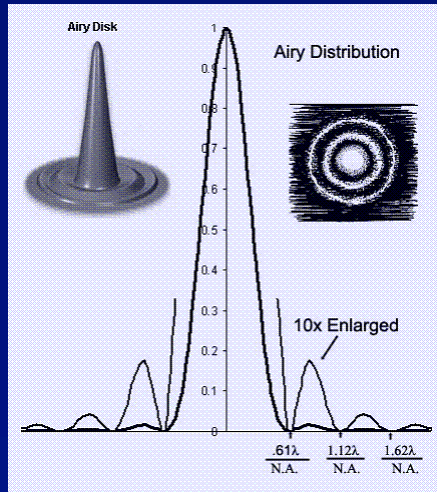
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Optical sub-wavelength imaging

- Backside optical techniques are critical to fault isolation and logic diagnostics on modern CMOS circuits.
- Backside optical resolution is limited by the wavelength of infra-red light.
- How can we “beat the resolution limit?”

Rayleigh Criterion



R = Resolution = $0.61 \lambda / \text{N.A.}$

N.A. = numerical aperture = $n \sin \theta$

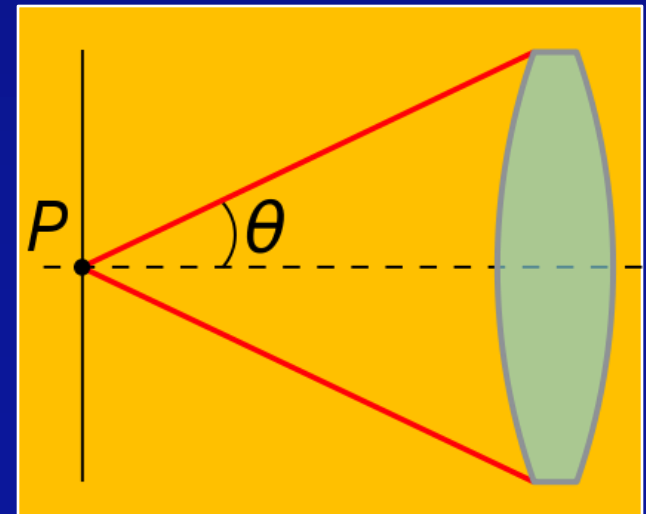
Where:

λ = wavelength of light

n = refractive index of the medium

the lens is operating in ($n = 1$ for air).

$\sin \theta \leq 0.95$



Rayleigh Criterion

For backside work, silicon is transparent above about 1 μm (1000 nm)

If:

$$\lambda = 1064 \text{ nm}$$

$$n = 1 \text{ (air)}$$

$$\sin \theta \sim 0.95$$

$$\text{Then Resolution } R = 0.61 \lambda / n \sin \theta = 680 \text{ nm}$$

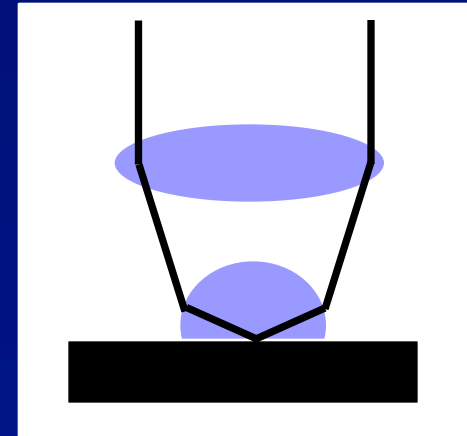
Note: For FI and debug we don't need resolution equal to the technology node.

Solid Immersion Lens

Refractive index of silicon is $n=3.6$

SIL Improves NA by 3.6

Resolution = $1000 \text{ nm} * 0.61 / 3.6 * 0.95$
= 180 nm



Lens

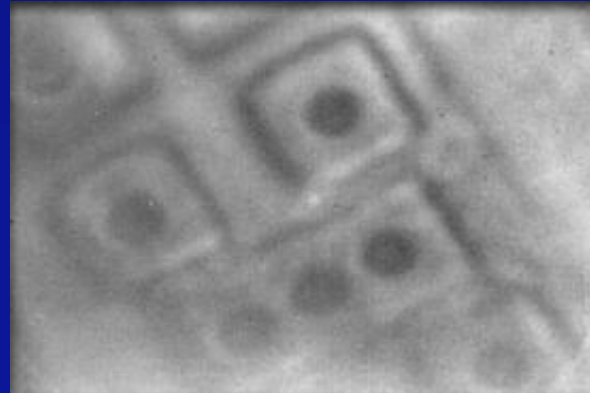
SIL

Si Chip

Without SIL



With SIL



Images with 100x objective

2 μm 

Solid Immersion Lens

3.6x is a HUGE improvement in resolution.

Relatively inexpensive and easy to use.

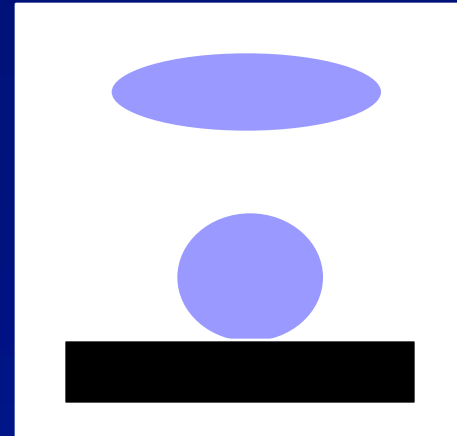
**Can be used for photons in (laser probing)
and photons out (photo emission).**

SIL Improvements?

1. Weierstrass SIL (Super-hemispherical SIL)

N.A. $\sim n^2$

- However, N.A. = numerical aperture = $n \sin \theta$ cannot exceed N.A. = n .



2. Choose SIL material with $N > 3.6$?

- Best SIL has same index as the substrate material.

3. Other ideas?

Near-Field Scanning Optical Microscopy

Rayleigh Criteria does not apply in the near field, i.e. within $\sim \lambda$ of the object.

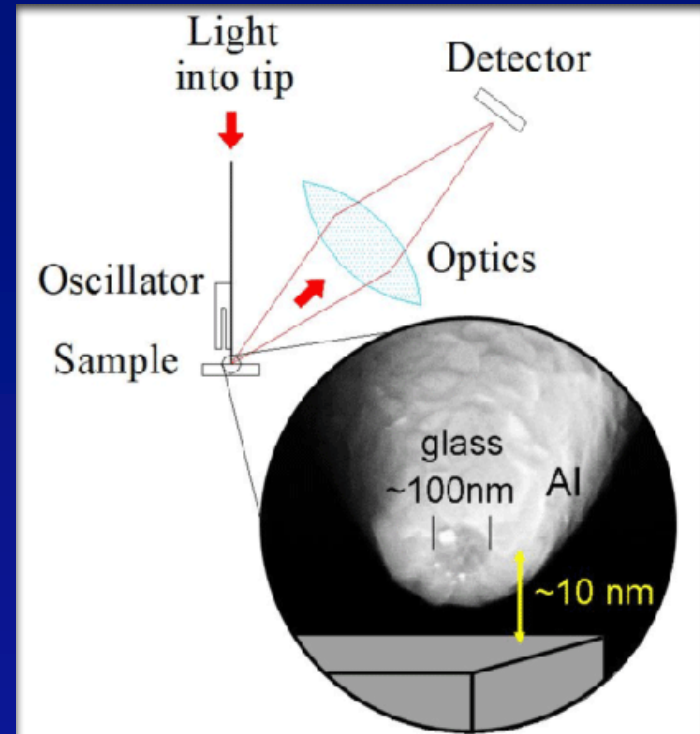
Technology:

- Nominal resolution = 50 nm
- Can be used for photons in (laser probing) and photons out (photo emission).
- NSOM / photo-emission proven (Isakov et al., ISTFA 2008)

Challenges:

- Cannot be combined with SIL
- Scanned technique – slow to collect large image
- Limited signal collection
- Must be very close - sample preparation issue

Note: silicon < 100 nm thick is transparent to shorter λ



Meta-Material hyper-lens

Negative index materials ($n < 0$)

“negative refraction”

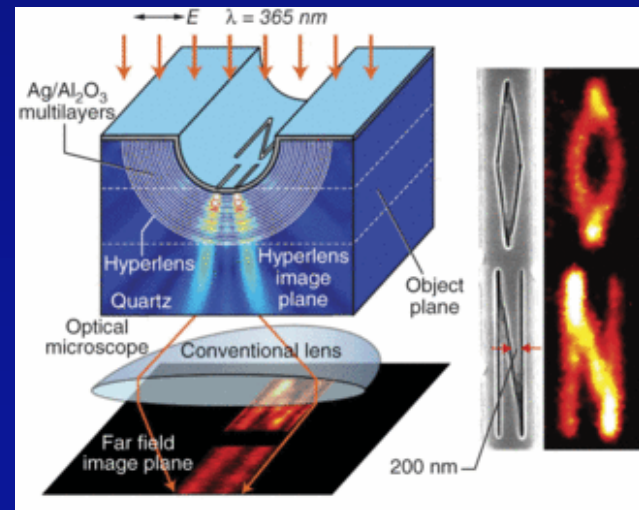
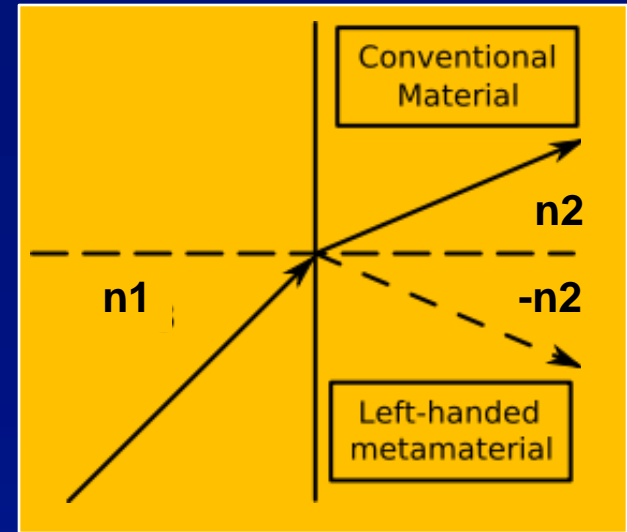
“cloak of invisibility”

Technology:

- Sub-wavelength imaging demonstrated
- Can be used for photons in (laser probing) and photons out (photo emission).

Challenges:

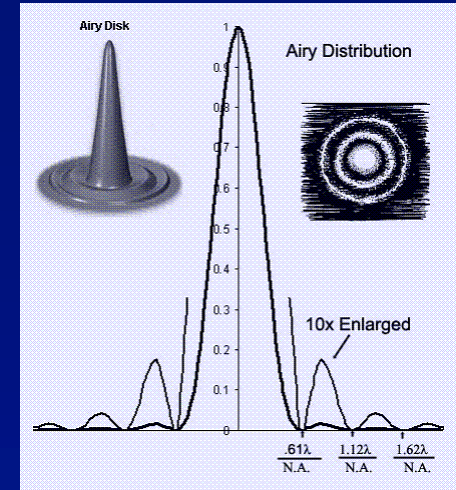
- Demonstrated resolution is limited
- Cannot be combined with SIL
- Must be very close - sample preparation issue



Zhang, et al., UC Berkeley

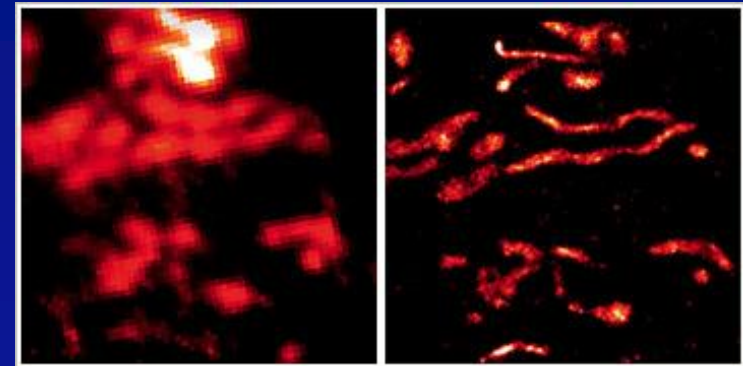
Point Spread Function Fitting

Photo-activated localization microscopy (PALM) or Stochastic optical reconstruction microscopy (STORM)
Sparsely populated point sources can be localized by curve fitting routines.



Technology:

- 20 nm resolution demonstrated (biological samples).
- May be combined with SIL



Eric Betzig, et al., Howard Hughes Medical Institute

Challenges:

- Cannot be used for photons in (laser probing)
- Requires a lot of photons
- CMOS photo emitters may not be sparsely populated

Entangled Photon Imaging

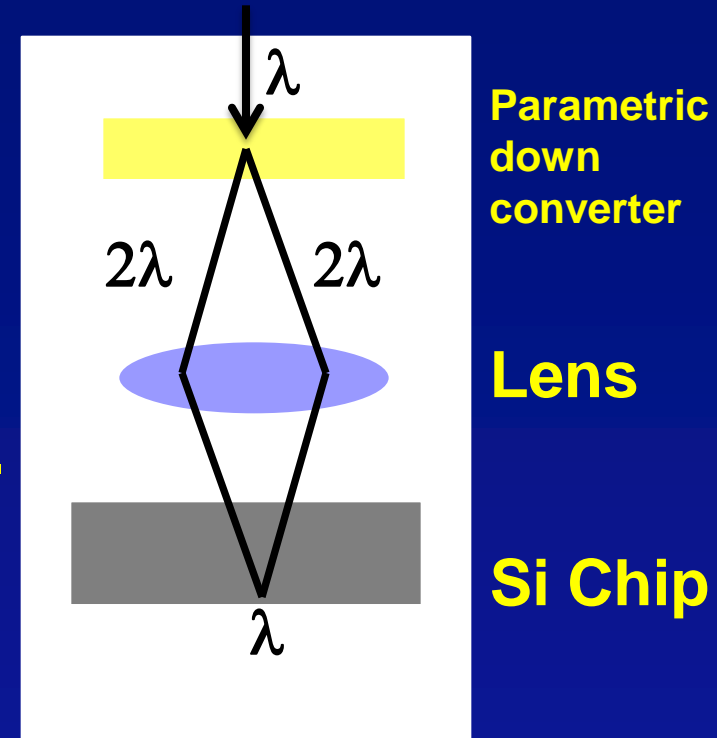
“Entangled photons” can be recombined to form one photon with half the wavelength

Technology:

- $N = 2$ gives 2x better resolution
- $N = 4$ gives 4x better resolution, etc.
- May be combined with SIL

Challenges:

- Little experimental data
- Cannot be used for photons out (photo emission)
- Entangled photon sources only a few % efficient



Interference Microscopy

Interference Microscope splits and recombined a beam to form an interference pattern.

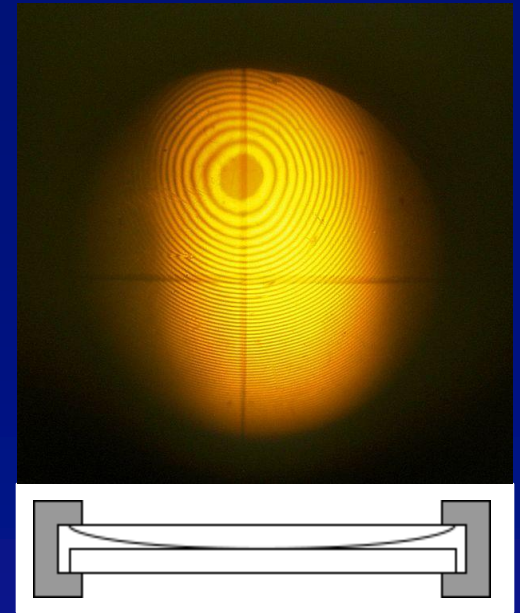
Can measure Z step height differences on thin films with 1 Å precision (X and Y precision much poorer, $\sim\lambda$)

Technology:

- Various sources claim that the technique can be generalized to 3-D

Challenges:

- Little experimental data
- Metrology tool, not useful for photo emission or laser probing



Newton's Rings